

AMENDMENTS TO THE CLAIMS

Please amend claims 1-5, 7, 8, 12-14, 18, 20-28, 32-34, and 37, and cancel claims 11 and 31, as set forth in the listing of claims that follows:

1. (Currently Amended) An edge-connected non-thermal plasma reactor element comprising:

an edge-connected frame comprising a pair of dielectric edge connectors secured at opposite ends to first and second outer dielectric plates to provide said edge-connected frame;

said dielectric edge connectors comprising a backplane and a plurality of tines protruding along at least one major surface of said backplane, said plurality of tines being spaced apart from one another at regular intervals so as to form pockets between adjacent tines; and

a plurality of alternating polarity electrode plates, each electrode plate comprising a dielectric barrier plate having an edge received within a pocket and an electrode on the barrier plate spaced apart from the edge by a setback and having a terminal connection lead, having an electrode and terminal connection lead disposed on said dielectric barrier plate, said electrode plates disposed within said frame in an arrangement that defines the presence of at least one dielectric barrier plate next to a plasma cell, said pockets engaging opposite ends of said electrode plates.

2. (Currently Amended) The element of claim 1, comprising a double dielectric barrier edge-connected element having plasma cells bounded on top and bottom by dielectric plates.

3. (Currently Amended) The element of claim 1, comprising a double ~~dielectric dielectric~~ barrier edge-connected element having a plurality of mirror image electrode plate pairs disposed in said pockets of said edge-connected frame, said electrode plate pairs arranged so that their electrodes are sandwiched between each electrode plate pair whereby plasma cells formed between adjacent electrode plate pairs are bounded on top and bottom walls by a dielectric barrier plate.

4. (Currently Amended) The element of claim 1, comprising a double ~~dielectric dielectric~~ barrier edge-connected element having a plurality of mirror image electrode plate pairs disposed in said pockets of said edge-connected frame, said electrode plate pairs arranged so that their electrodes are sandwiched between each electrode plate pair whereby plasma cells formed between adjacent electrode plate pairs are bounded on top and bottom walls by a dielectric barrier plate; and

top and bottom most pockets have electrode plate-dielectric barrier plate pairs, said electrodes facing away from said plasma cell, disposed therein.

5. (Currently Amended) The element of claim 1, comprising a double dielectric barrier edge-connected element having a plurality of mirror image electrode plate pairs disposed in said pockets of said edge-connected frame, said electrode plate pairs arranged so that their electrodes are sandwiched between each electrode plate pair whereby plasma cells formed between adjacent electrode plate pairs are bounded on top and bottom walls by a dielectric barrier plate;

a single electrode plate disposed in a top pocket formed between said first outer dielectric plate and said times adjacent said first outer dielectric plate;

a single electrode plate disposed in a bottom pocket formed between said second outer dielectric plate and said times adjacent said second outer dielectric plate;

whereby top and bottom most plasma cells are bounded on top and bottom by a dielectric barrier plate.

6. (Original) The element of claim 1, comprising a double dielectric barrier edge-connected element having a plurality of electrode plates disposed in said pockets of said edge-connected frame, said electrode plates having a dielectric plate-electrode-dielectric plate arrangement, wherein a single electrode is sandwiched between said dielectric plates in sufficiently close contact to both dielectric layers to avoid gaps between said electrode and said dielectric plates that would cause parasitic arcing.

7. (Currently Amended) The element of claim 1, comprising a single dielectric barrier edge-connected element, having plasma cells bounded on one side by a dielectric plate and on an opposite side by an electrode.

8. (Currently Amended) The element of claim 1, comprising a single dielectric barrier edge-connected element, wherein a single electrode plate is disposed in said pockets of said edge-connected frame to effect an alternating polarity arrangement wherein plasma cells are bounded on one side by a dielectric plate and on an opposite side by an electrode.

9. (Original) The element of claim 1, wherein said backplane comprises a gripping surface on a surface opposite said tines.

10. (Original) The element of claim 1, wherein said pockets have a first width; and

top and bottom pockets formed by said outer dielectric plates and tines adjacent said outer dielectric plates have a second width that is half that of said first width.

11. (Cancelled)

12. (Currently Amended) The element of claim 1, wherein the setback between the edge of the barrier plate and the electrode is less than about 5 millimeters ~~further comprising an electrode pattern having a small setback wherein said electrode extends to within about 5 millimeters from edges of said dielectric plate engaging said tines.~~

13. (Currently Amended) The element of claim 1, wherein setback is less than the height of the tine ~~a distance between a front edge of said dielectric barrier electrode plate to a proximate edge of said electrode is large relative to the thickness of said tines.~~

14. (Currently Amended) The element of claim 1, wherein said dielectric edge connectors are composed of a dielectric material ~~comprise a low dielectric constant material or a high dielectric constant material in combination with a low dielectric constant constituent.~~

15. (Original) The element of claim 1, wherein said edge connectors comprise linking edge connectors having a central backplane and a plurality of tines protruding along two opposite major surfaces of said backplane, said plurality of tines being spaced apart from one another at regular intervals so as to form pockets between adjacent tines.

16. (Original) The element of claim 1, wherein said edge-connected frame comprises an integral frame.

17. (Original) The element of claim 1, wherein said edge-connected frame comprises discrete edge connector and outer dielectric plate sections joined together to form said edge-connected frame.

18. (Currently Amended) A non-thermal plasma reactor having an edge-connected element comprising:

an edge-connected frame comprising a pair of dielectric edge connectors secured at opposite ends to first and second outer dielectric plates to provide said edge-connected frame;

said dielectric edge connectors comprising a backplane and a plurality of tines protruding along at least one major surface of said backplane, said plurality of tines being spaced apart from one another at regular intervals so as to form pockets between adjacent tines; and

a plurality of alternating polarity electrode plates, each electrode plate comprising a dielectric barrier plate having an edge received within a pocket and an electrode on the barrier plate spaced apart from the edge by a setback and having a terminal connection lead, having an electrode and terminal connection lead disposed on said dielectric barrier plate, said electrode plates disposed within said frame in an arrangement that defines the presence of at least one dielectric barrier next to a plasma cell, said pockets engaging opposite ends of said electrode plates;

a ~~high-temperature~~ housing surrounding said edge-connected element and spaced therefrom by a retention mat supporting said edge-connected element in said housing;

an inlet for admitting a stream to be treated into said plasma cells;

an outlet for discharging a treated fluid stream from said plasma cells;

a power bus path for connecting power electrode plates to a high voltage source;

a ground bus path for connecting the ground electrodes to ground; and

means for directing said fluid stream through said plasma cells.

19. (Original) The reactor of claim 18, wherein electrode plates are rigidly connected to said edge-connected frame at front or rear of said reactor element and are otherwise compliantly supported by said pockets thereby providing electrode plates that are free to expand within the edge-connected frame in response to thermally induced stress.

20. (Currently Amended) The reactor of claim 19, further comprising a dielectric, ~~high temperature~~ adhesive attaching ~~disposed at either front or rear of said element to fasten~~ said electrode plates to said edge connected frame, said adhesive being disposed over and around said bus paths to fix and protect said bus paths and secure the element assembly together.

21. (Currently Amended) The reactor of claim 18, wherein said retention mat comprises a dielectric retention mat providing a compliant pressure against exterior portions of said reactor element adjacent said housing and front and rear end portions of said reactor element, thereby providing compliant fixturing for said electrode plates packaged in said housing.

22. (Currently Amended) The reactor of claim 18, comprising a double dielectric barrier edge-connected element having plasma cells bounded on top and bottom by dielectric plates.

23. (Currently Amended) The reactor of claim 18, comprising a double dielectric barrier edge-connected element having a plurality of mirror image electrode plate pairs disposed in said pockets of said edge-connected frame, said electrode plate pairs arranged so that their electrodes are sandwiched between each electrode plate pair whereby plasma cells formed between adjacent electrode plate pairs are bounded ~~on top and bottom walls~~ by a dielectric barrier plates.

24. (Currently Amended) The reactor of claim 18, comprising a double dielectric barrier edge-connected element having a plurality of mirror image electrode plate pairs disposed in said pockets of said edge-connected frame, said electrode plate pairs arranged so that their electrodes are sandwiched between each electrode plate pair whereby plasma cells formed between adjacent electrode plate pairs are bounded ~~on top and bottom walls~~ by a dielectric barrier plates; and

top and bottom ~~most~~ pockets have electrode plate-dielectric barrier plate pairs, said electrodes facing away from said plasma cell, disposed therein.

25. (Currently Amended) The reactor of claim 18, comprising a double dielectric barrier edge-connected element having a plurality of mirror image electrode plate pairs disposed in said pockets of said edge-connected frame, said electrode plate pairs arranged so that their electrodes are sandwiched between each electrode plate pair whereby plasma cells formed between adjacent electrode plate pairs are bounded ~~on top and bottom walls~~ by a dielectric barrier plates;

a single electrode plate disposed in a top pocket formed between said first outer dielectric plate and said lines adjacent said first outer dielectric plate;

a single electrode plate disposed in a bottom pocket formed between said second outer dielectric plate and said lines adjacent said second outer dielectric plate;

whereby top and bottom ~~most~~ plasma cells are bounded on top and bottom by a dielectric barrier plates.

26. (Currently Amended) The reactor of claim 18, comprising a double dielectric barrier edge-connected element having a plurality of electrode plates disposed in said pockets of said edge-connected frame, said electrode plates having a dielectric plate-electrode-dielectric plate arrangement, wherein a single electrode is sandwiched between said dielectric barrier plates in contact therewith ~~sufficiently close contact to both dielectric layers~~ to avoid gaps between said electrode and said dielectric barrier plates that would cause parasitic arcing.

27. (Currently Amended) The reactor of claim 18, comprising a single dielectric barrier edge-connected element, having plasma cells bounded on one side by a dielectric plate and on an opposite side by an electrode.

28. (Currently Amended) The reactor of claim 18, comprising a single dielectric barrier edged-connected element, wherein a single electrode plate is disposed in said pockets of said edge-connected frame to effect an alternating polarity arrangement wherein plasma cells are bounded on one side by a dielectric plate and on an opposite side by an electrode.

29. (Original) The reactor of claim 18, wherein said backplane comprises a gripping surface on a surface opposite said tines.

30. (Original) The reactor of claim 18, wherein a majority of said pockets have a first width; and
top and bottom pockets formed by said outer dielectric plates and tines adjacent said outer dielectric plates have a second width that is half that of said first width.

31. (Cancelled).

32. (Currently Amended) The reactor of claim 18, wherein the setback between the edge of the barrier plate and the electrode is less than about 5 millimeters ~~further comprising an electrode pattern having a small setback wherein said electrode extends to within about 5 millimeters from edges of said dielectric plate engaging said tines.~~

33. (Currently Amended) The reactor of claim 18, wherein the setback is less than the height of the tine ~~a distance between a front edge of said dielectric barrier electrode plate to a proximate edge of said electrode is large relative to the thickness of said tines.~~

34. (Currently Amended) The reactor of claim 18, wherein said dielectric edge connectors are composed of dielectric material ~~comprise a low dielectric constant material or a high dielectric constant material in combination with a low dielectric constant constituent.~~

35. (Original) The reactor of claim 18, wherein said edge connectors comprise linking edge connectors having a central backplane and a plurality of tines protruding along two opposite major surfaces of said backplane, said plurality of tines being spaced apart from one another at regular intervals so as to form pockets between adjacent tines.

36. (Original) The reactor of claim 18, wherein said backplane is continuous over opposite sides of said edge-connected non-thermal plasma reactor element when assembled thereby preventing charge leakage.

37. (Currently Amended) The reactor of claim 18, wherein said gripping surface of said backplane further serves to create a tortuous path between said backplane and said mat material thereby reducing the potential for untreated gas to leak between said backplane and said retention mat.

38. (Original) The reactor of claim 18, wherein said edge-connected frame comprises an integral frame.

39. (Original) The reactor of claim 18, wherein said edge-connected frame comprises discrete edge connector and outer dielectric plate sections joined together to form said edge-connected frame.